2.5V Drive Pch MOSFET

RTF020P02

●Structure

Silicon P-channel MOSFET

● Features

- 1) Low on-resistance. (120m Ω at 2.5V)
- 2) High power package.
- 3) High speed switching.
- 4) Low voltage drive. (2.5V)

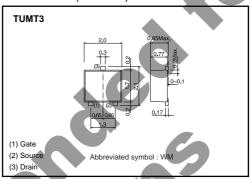
Applications

DC-DC converter

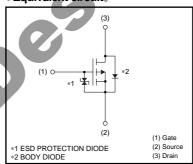
Packaging specifications

	Package	Taping		
Type	Code	TL		
	Basic ordering unit (pieces)	3000		
RTF020P02	0			

●Dimensions (Unit:mm)



●Equivalent circuit



● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Drain-source voltage	V _{DSS}	-20	V		
Gate-source voltage		V _{GSS}	±12	V	
Drain current	Continuous	I_{D}	±2.0	Α	
Drain current	Pulsed	I _{DP} *1	±8	Α	
Source current	Continuous	Is *1	-0.6	Α	
(Body diode)	Pulsed	I _{SP}	-8	Α	
Total power dissipation	P _D *2	0.8	W		
Channel temperature	Tch	150	°C		
Range of Storage temperatu	Tstg	-55 to +150	°C		

^{*1} Pw≤10μs, Duty cycle≤1% *2 Mounted on a ceramic board

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth(ch-a) *	156	°C / W

^{*} Mounted on a ceramic board.

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	Igss	_	_	±10	μА	Vgs=±12V, Vps=0V
Drain-source breakdown voltage	V _{(BR) DSS}	-20	_	_	V	I _D = -1mA, V _{GS} =0V
Zero gate voltage drain current	I _{DSS}	_	_	-1	μΑ	V _{DS} = -20V, V _{GS} =0V
Gate threshold voltage	V _{GS (th)}	-0.7	_	-2.0	V	$V_{DS} = -10V, I_{D} = -1mA$
Static drain-source on-state resistance	*	_	60	85	mΩ	I _D = -2A, V _G S= -4.5V
	R _{DS} (on)	_	65	90	mΩ	I _D = -2A, V _G S= -4V
resistance		_	120	165	mΩ	I _D = -1A, V _G S= -2.5V
Forward transfer admittance	Y _{fs} *	2.0	_	_	S	V _{DS} = -10V, I _D = -1A
Input capacitance	Ciss	_	640	_	pF	V _{DS} = -10V
Output capacitance	Coss	_	110	_	pF	Vgs=0V
Reverse transfer capacitance	Crss	_	85	_	pF	f=1MHz
Turn-on delay time	t _{d (on)} *	_	12	_	ns	ID= -1A
Rise time	tr *	_	15	_	ns	V _{DD} = −15V V _{GS} = −4.5V
Turn-off delay time	t _{d (off)} *	_	40	_	ns	$R_L=15\Omega$
Fall time	t _f *	_	12	_	ns	R _G =10Ω
Total gate charge	Qg *	-	7.0	-	nC	V _{DD} ≒−15V R _L =7.5Ω
Gate-source charge	Q _{gs} *	_	1.6	-	nC	$V_{GS} = -4.5V$ Rg=10 Ω
Gate-drain charge	Q _{gd} *	_	2.0	_	nC	I _D =-2A

*Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

Body diode characterist Parameter	Symbol		Typ.	Max.	Unit	Conditions
Forward voltage	Vsp	- IVIII 1.	тур. —	-1.2	V	I _S = -0.6A, V _G S=0V
Polward voltage	VSD					IS= -0.0A, V6S≡UV



•Electrical characteristic curves

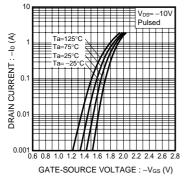


Fig.1 Typical Transfer Characteristics

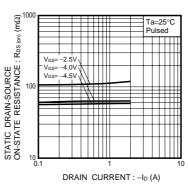


Fig.2 Static Drain-Source On-State Resistance vs. Drain Current

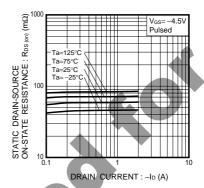


Fig.3 Static Drain-Source On-State Resistance vs. Drain Current

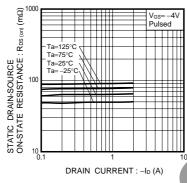


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current

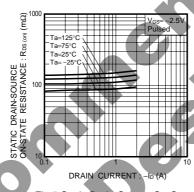


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current

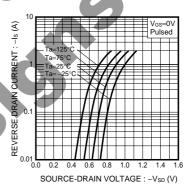


Fig.6 Reverse Drain Current vs. Source-Drain Voltage

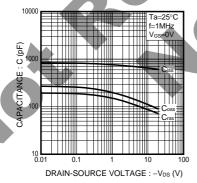


Fig.7 Typical Capacitance vs. Drain-Source Voltage

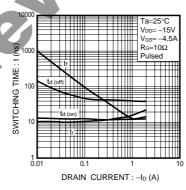


Fig.8 Switching Characteristics

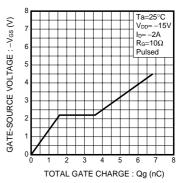


Fig.9 Dynamic Input Characteristics

●Measurement circuits

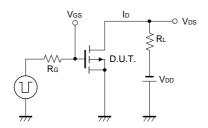


Fig.10 Switching Time Measurement Circuit

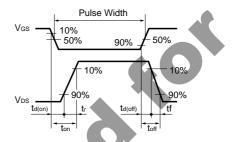


Fig.11 Switching Waveforms

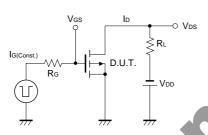


Fig.12 Gate Charge Measurement Circuit

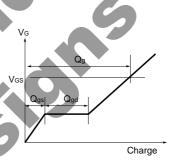


Fig.13 Gate Charge Waveforms

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